

SURFACE MOUNT SCHOTTKY BARRIER DIODE ARRAYS

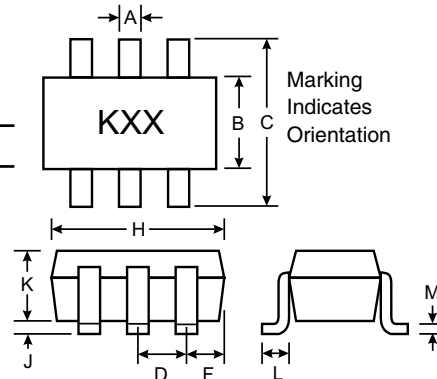
NEW PRODUCT

Features

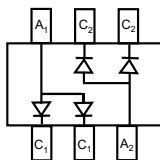
- Low Forward Voltage Drop
- Fast Switching
- Ultra-Small Surface Mount Package
- PN Junction Guard Ring for Transient and ESD Protection

Mechanical Data

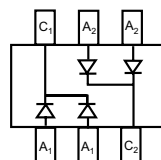
- Case: SOT-363, Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagrams Below
- Weight: 0.006 grams (approx.)



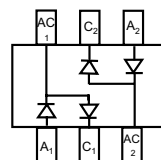
SOT-363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
E	0.30	0.40
G	1.80	2.20
H	1.80	2.20
J	—	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.25
All Dimensions in mm		



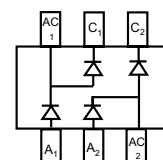
BAS40DW-06
Marking: K46



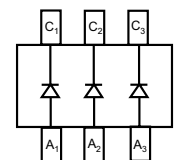
BAS40DW-05
Marking: K45



BAS40DW-04
Marking: K44



BAS40BRW
Marking: K47



BAS40TW
Marking: K43

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	40	V
RMS Reverse Voltage	V _{R(RMS)}	28	V
Forward Continuous Current (Note 1)	I _{FM}	200	mA
Non-Repetitive Peak Forward Surge Current @ t < 1.0s	I _{FSM}	600	mA
Power Dissipation (Note 1)	P _d	200	mW
Thermal Resistance Junction to Ambient Air (Note 1)	R _{θJA}	625	K/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +125 -65 to +125	°C

Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Maximum Forward Voltage	V _{FM}	—	370 1000	mV mV	I _F = 1.0mA, t _p < 300μs I _F = 40mA, t _p < 300μs
Maximum Peak Reverse Current	I _{RM}	—	200	nA	V _R = 30V
Junction Capacitance	C _j	—	5.0	pF	V _R = 0, f = 1.0MHz
Reverse Recovery Time	t _{rr}	—	5.0	ns	I _F = I _R = 10mA, I _{rr} = 0.1 x I _R , R _L = 100Ω

Notes: 1. Valid Provided that terminals are kept at ambient temperature.